

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

NEC

The NP160N04TUG is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE		
NP160N04TUG-E1-AY Note	Pure Sn (Tin)	Tape 800 p/reel	TO-263-7pin (MP-25ZT) typ. 1.5 g		
NP160N04TUG-E2-AY Note					

Note Pb-free (This product does not contain Pb in the external electrode).

FEATURES

Super low on-state resistance

 $R_{DS(on)}$ = 1.6 m Ω TYP. / 2.0 m Ω MAX. (V_{GS} = 10 V, I_D = 80 A)

High Current Rating

 $I_{D(DC)}$ = ±160 A

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	40	V
Gate to Source Voltage (VDs = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	D(DC)	±160	А
Drain Current (pulse) ^{Note1}	D(pulse)	±640	А
Total Power Dissipation (Tc = 25°C)	P _{T1}	220	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.8	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to +175	°C
Single Avalanche Energy Note2	Eas	372	mJ
Repetitive Avalanche Current Note3	IAR	61	А
Repetitive Avalanche Energy Note3	Ear	372	mJ

NEC 102857

(TO-263-7pin)

Notes 1.	PW ≤ 10 <i>μ</i> s,	Duty Cycle $\leq 1\%$
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2. Starting T_{ch} = 25°C, V_{DD} = 20 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H

3. RG = 25 Ω , Tch(peak) \leq 150°C

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	0.68	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 40 V, V _{GS} = 0 V			1	μA
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	2.0	3.0	4.0	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 5 V, I _D = 40 A	28	76		S
Drain to Source On-state Resistance Note	RDS(on)	V _{GS} = 10 V, I _D = 80 A		1.6	2.0	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V,		10500	15750	pF
Output Capacitance	Coss	V _{GS} = 0 V,		980	1470	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		630	1140	pF
Turn-on Delay Time	td(on)	V _{DD} = 20 V, I _D = 80 A,		47	110	ns
Rise Time	tr	V _{GS} = 10 V,		67	170	ns
Turn-off Delay Time	td(off)	R _G = 0 Ω		94	190	ns
Fall Time	tr			19	50	ns
Total Gate Charge Note	QG	V _{DD} = 32 V,		178	270	nC
Gate to Source Charge	QGS	Vgs = 10 V,		44		nC
Gate to Drain Charge	Qgd	I _D = 160 A		61		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	IF = 160 A, V _{GS} = 0 V		0.92	1.5	V
Reverse Recovery Time	trr	I⊧ = 160 A, V _{GS} = 0 V,		50		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		75		nC

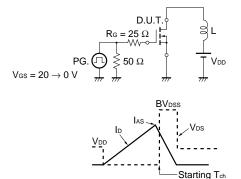
ELECTRICAL CHARACTERISTICS (TA = 25°C)

Note Pulsed test

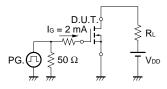
TEST CIRCUIT 1 AVALANCHE CAPABILITY

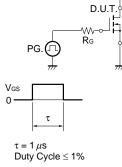
TEST CIRCUIT 2 SWITCHING TIME

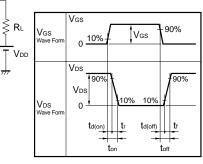
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TEST CIRCUIT 3 GATE CHARGE

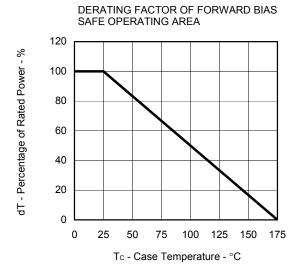




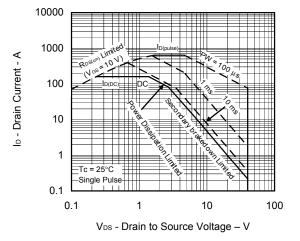


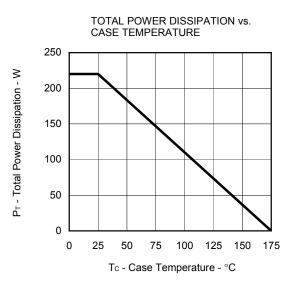
Data Sheet D18754EJ1V0DS

TYPICAL CHARACTERISTICS (TA = 25°C)

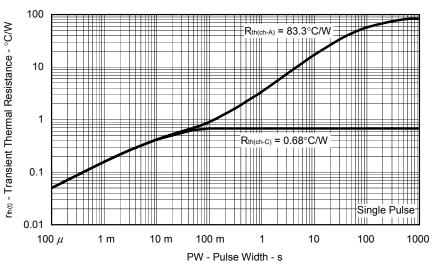




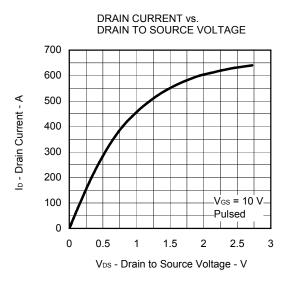




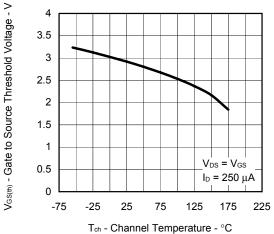




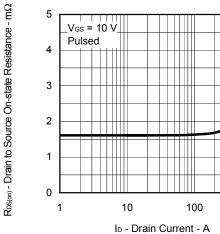
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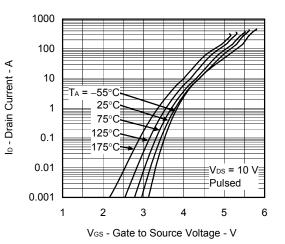




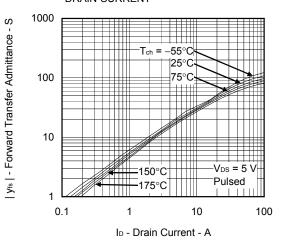
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



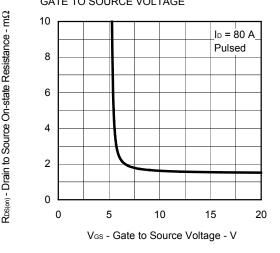
FORWARD TRANSFER CHARACTERISTICS



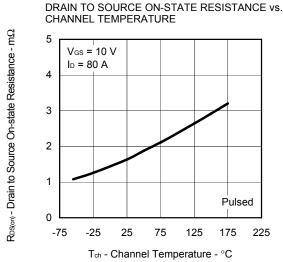
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

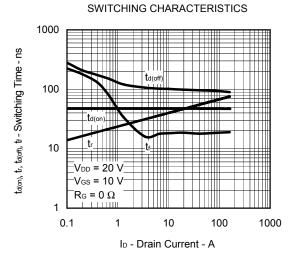


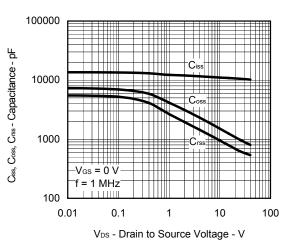




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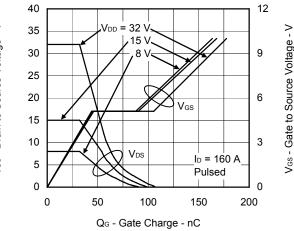


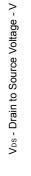


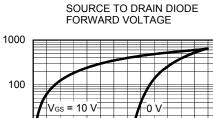


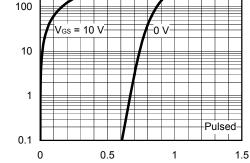
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

DYNAMIC INPUT/OUTPUT CHARACTERISTICS





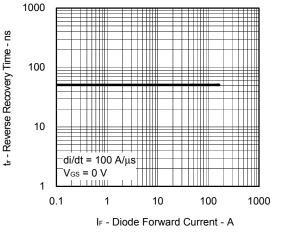




IF - Diode Forward Current - A

 $V_{F(S-D)}$ - Source to Drain Voltage - V

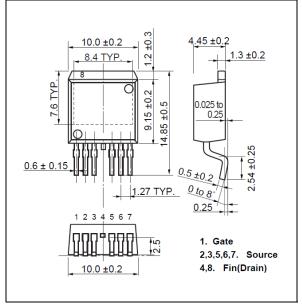




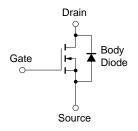
Data Sheet D18754EJ1V0DS

PACKAGE DRAWING (Unit: mm)

TO-263-7pin (MP-25ZT)



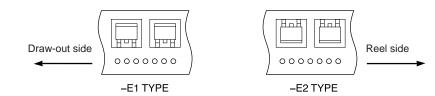
EQUIVALENT CIRCUIT



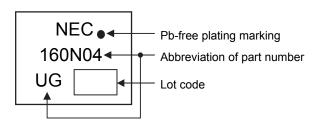
Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

The NP160N04TUG should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol		
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below			
	Time at maximum temperature: 10 seconds or less			
	Time of temperature higher than 220°C: 60 seconds or less			
	Preheating time at 160 to 180°C: 60 to 120 seconds	IR60-00-3		
	Maximum number of reflow processes: 3 times			
	Maximum chlorine content of rosin flux (percentage mass): 0.2% or less			
Partial heating	Maximum temperature (Pin temperature): 350°C or below			
	Time (per side of the device): 3 seconds or less	P350		
	Maximum chlorine content of rosin flux: 0.2% (wt.) or less			

Caution Do not use different soldering methods together (except for partial heating).

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